

# 45V/60V/80V, 1A NPN medium power transistors Rev. 1 — 11 November 2014 Pro

Product data sheet

#### **Product profile**

#### 1.1 General description

NPN medium power transistor series encapsulated in an ultra thin DFN2020D-3 (SOT1061D) leadless small Surface-Mounted Device (SMD) plastic package with medium power capability and visible and solderable side pads.

Table 1. **Product overview** 

Type number[1]	Package	Package	
BC54PAS	DFN2020D-3	SOT1061D	BC51PAS
BC55PAS			BC52PAS
BC56PAS			BC53PAS

<sup>[1]</sup> Valid for all available selection groups.

#### 1.2 Features and benefits

- High collector current capability I<sub>C</sub> and  $I_{CM}$
- Reduced Printed-Circuit Board (PCB) area requirements
- Exposed heat sink for excellent thermal and electrical conductivity
- AEC-Q101 qualified

- Three current gain selections
- Leadless very small SMD plastic package with medium power capability
- Suitable for Automatic Optical Inspection (AOI) of solder joint

#### 1.3 Applications

- Linear voltage regulators
- Battery driven devices
- MOSFET drivers

- Low-side switches
- Power management
- Amplifiers

#### 1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base				
	BC54PAS		-	-	45	V
	BC55PAS		-	-	60	V
	BC56PAS		-	-	80	V
Ic	collector current		-	-	1	Α



45V/60V/80V, 1A NPN medium power transistors

Table 2. Quick reference data ...continued

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CM</sub>	peak collector current	single pulse; $t_p \le 1$ ms	-	-	2	Α
h <sub>FE</sub>	DC current gain	$V_{CE} = 2 \text{ V}; I_{C} = 150 \text{ mA}$	63	-	250	
	h <sub>FE</sub> selection -10	$V_{CE} = 2 \text{ V}; I_{C} = 150 \text{ mA}$ [1]	63	-	160	
	h <sub>FE</sub> selection -16	$V_{CE} = 2 \text{ V}; I_{C} = 150 \text{ mA}$	100	-	250	

[1] Pulse test:  $t_p \le 300 \ \mu s; \ \delta \le 0.02$ 

#### 2. Pinning information

Table 3. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	base		
2	emitter	3	3
3	collector	Transparent top view	12 sym021

# 3. Ordering information

Table 4. Ordering information

Type number[1]	Package			
	Name	Name Description		
BC54PAS	DFN2020D-3	DFN2020D-3: plastic thermal enhanced ultra thin small outline	SOT1061D	
BC55PAS		package; no leads; 3 terminals; body 2 × 2 × 0.65 mm.		
BC56PAS				

[1] Valid for all available selection groups.

#### 4. Marking

Table 5. Marking codes

Type number	Marking code
BC54PAS	CD
BC54-10PAS	CE
BC54-16-PAS	CF
BC55PAS	CG
BC55-10PAS	СН
BC55-16PAS	CJ
BC56PAS	CK
BC56-10PAS	CL
BC56-16PAS	СМ

# 5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

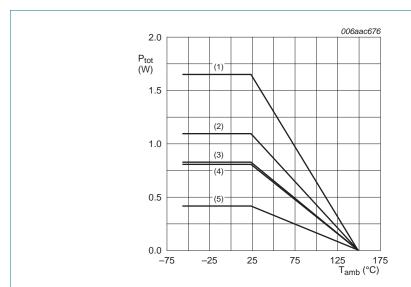
Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter			
	BC54PAS		-	45	V
	BC55PAS		-	60	V
	BC56PAS		-	100	V
$V_{CEO}$	collector-emitter voltage	open base			
	BC54PAS		-	45	V
	BC55PAS		-	60	V
	BC56PAS		-	80	V
$V_{EBO}$	emitter-base voltage	open collector	-	5	V
I <sub>C</sub>	collector current		-	1	А
I <sub>CM</sub>	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	2	A
I <sub>B</sub>	base current		-	0.3	А

Table 6. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$	1 -	0.42	W
		[2	1 -	0.81	W
		[3	-	0.83	W
		[4	1 -	1.10	W
		<u>[5</u>	il -	1.65	W
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-55	150	°C
T <sub>stg</sub>	storage temperature		-65	150	°C

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 1 cm<sup>2</sup>.
- [4] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 6 cm<sup>2</sup>.
- [5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and mounting pad for collector 1 cm<sup>2</sup>.



- (1) FR4 PCB, 4-layer copper, 1 cm<sup>2</sup>
- (2) FR4 PCB, single-sided copper, 6 cm<sup>2</sup>
- (3) FR4 PCB, single-sided copper, 1 cm<sup>2</sup>
- (4) FR4 PCB, 4-layer copper, standard footprint
- (5) FR4 PCB, single-sided copper, standard footprint

Fig 1. Power derating curves

#### 6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions		Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction	in free air	<u>[1]</u>	298	K/W
	to ambient	-	[2]	154	K/W
			[3]	151	K/W
			[4]	114	K/W
			[5]	76	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point	in free air		20	K/W

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 1 cm<sup>2</sup>.
- [4] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 6 cm<sup>2</sup>.
- [5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and mounting pad for collector 1 cm<sup>2</sup>.

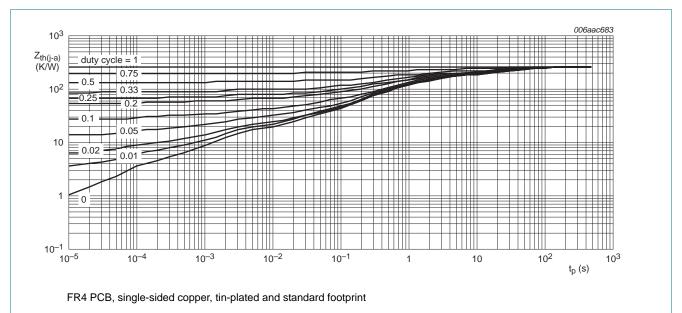
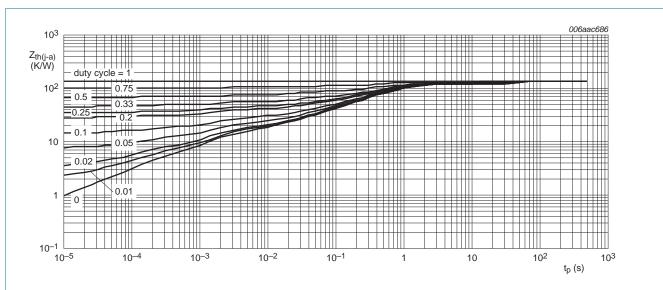
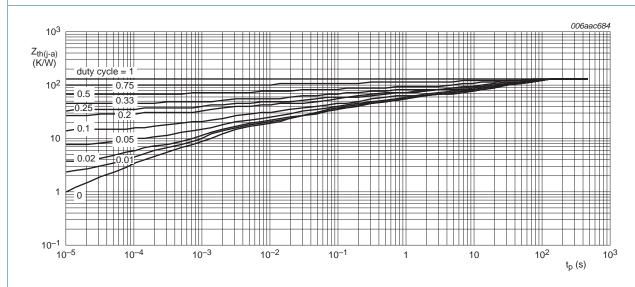


Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



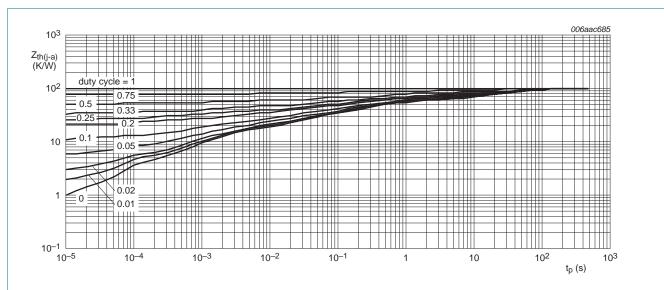
FR4 PCB, 4-layer copper, tin-plated and standard footprint

Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



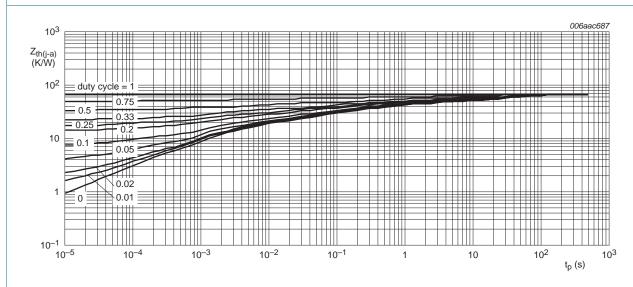
FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 1 cm<sup>2</sup>

Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 6 cm<sup>2</sup>

Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, 4-layer copper, tin-plated and mounting pad for collector 1 cm<sup>2</sup>

Fig 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

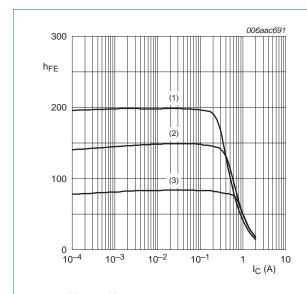
#### 7. Characteristics

Table 8. Characteristics

T<sub>amb</sub> = 25 °C unless otherwise specified

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off current	V <sub>CB</sub> = 30 V; I <sub>E</sub> = 0 A		-	-	100	nA
		$V_{CB} = 30 \text{ V}; I_E = 0 \text{ A}; T_j = 150 ^{\circ}\text{C}$		-	-	10	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0 A		-	-	100	nA
h <sub>FE</sub>	DC current gain	$V_{CE} = 2 \text{ V}; I_C = 5 \text{ mA}$		63	-	-	
	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 150 mA	<u>[1]</u>	63	-	250		
	$V_{CE} = 2 \text{ V}; I_{C} = 500 \text{ mA}$	<u>[1]</u>	40	-	-		
	h <sub>FE</sub> selection -10	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 150 mA	<u>[1]</u>	63	-	160	
	h <sub>FE</sub> selection -16	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 150 mA	<u>[1]</u>	100	-	250	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = 500 \text{ mA}; I_B = 50 \text{ mA}$	<u>[1]</u>	-	-	500	mV
$V_{BE}$	base-emitter voltage	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 500 mA	<u>[1]</u>	-	-	1	V
C <sub>c</sub>	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}$		-	6	-	pF
f <sub>T</sub>	transition frequency	$V_{CE} = 5 \text{ V}; I_{C} = 50 \text{ mA}; f = 100 \text{ MHz}$		100	180	-	MHz

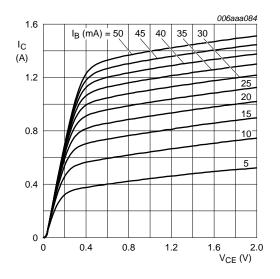
#### [1] Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02$





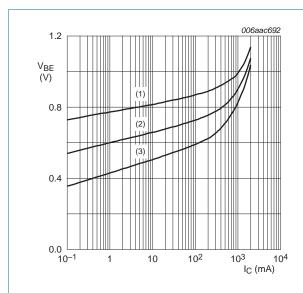
- (1)  $T_{amb} = 100 \, ^{\circ}C$
- (2)  $T_{amb} = 25 \, ^{\circ}C$
- (3)  $T_{amb} = -55 \, ^{\circ}C$

Fig 7. DC current gain as a function of collector current; typical values



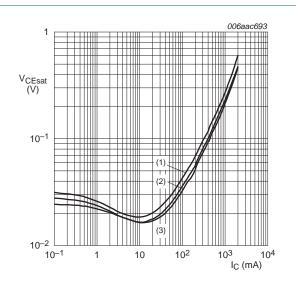
 $T_{amb}$  = 25 °C

Fig 8. Collector current as a function of collector-emitter voltage; typical values



- $V_{CE} = 2 V$
- (1)  $T_{amb} = -55 \, ^{\circ}C$
- (2)  $T_{amb} = 25 \, ^{\circ}C$
- (3) T<sub>amb</sub> = 100 °C

Fig 9. Base-emitter voltage as a function of collector current; typical values



- $I_{\rm C}/I_{\rm B} = 10$
- (1)  $T_{amb} = 100 \, ^{\circ}C$
- (2)  $T_{amb} = 25 \, ^{\circ}C$
- (3)  $T_{amb} = -55 \, ^{\circ}C$

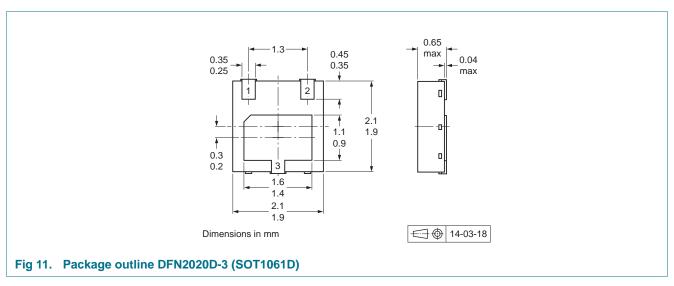
Fig 10. Collector-emitter saturation voltage as a function of collector current; typical values

#### 8. Test information

#### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

#### 9. Package outline

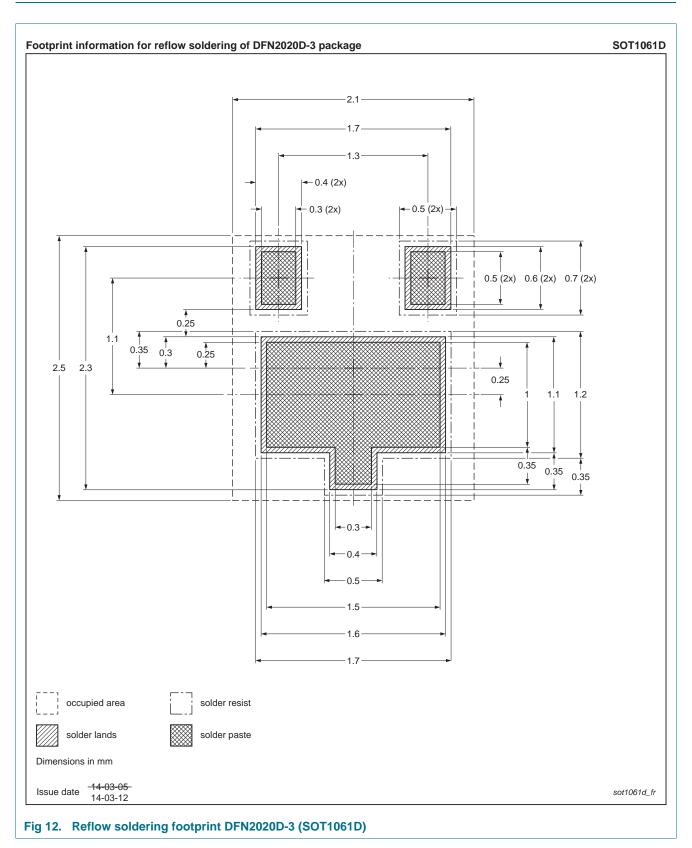


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# 10. Soldering



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#### 11. Revision history

#### Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BC54_55_56PAS_SER v.1	20141111	Product data sheet	-	-

#### 12. Legal information

#### 12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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#### 14. Contents

1	Product profile
1.1	General description 1
1.2	Features and benefits
1.3	Applications
1.4	Quick reference data 1
2	Pinning information 2
3	Ordering information 2
4	Marking 3
5	Limiting values 3
6	Thermal characteristics 5
7	Characteristics 8
8	Test information 9
8.1	Quality information 9
9	Package outline 9
10	Soldering 10
11	Revision history 11
12	Legal information 12
12.1	Data sheet status
12.2	Definitions
12.3	Disclaimers
12.4	Trademarks 13
13	Contact information
14	Contents 14

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401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd Minhang District, Shanghai , China

#### > Sales:

Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

Skype ameyasales1 ameyasales2

#### Customer Service :

Email service@ameya360.com

# Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com